

## Absolute maximum ratings

(Ta=25°C)

| Symbol                | Ratings   | Unit |
|-----------------------|---|------|
| V <sub>DSS</sub>      | 250   | V    |
| V <sub>GSS</sub>      | ±20   | V    |
| I <sub>D</sub>        | ±7  | A    |
| I <sub>D(pulse)</sub> | ±15 (PW≤1ms, Du≤1%)   | A    |
| E <sub>AS*</sub>      | 120   | mJ   |
| P <sub>T</sub>        | 4 (Ta=25°C, with all circuits operating, without heatsink)<br>35 (Tc=25°C, with all circuits operating, with infinite heatsink) | W    |
| θ <sub>j-a</sub>      | 31.2 (Junction-Air, Ta=25°C, with all circuits operating)   | °C/W |
| θ <sub>j-c</sub>      | 3.57 (Junction-Case, Tc=25°C, with all circuits operating)  | °C/W |
| T <sub>ch</sub>       | 150   | °C   |
| T <sub>stg</sub>      | -40 to +150   | °C   |

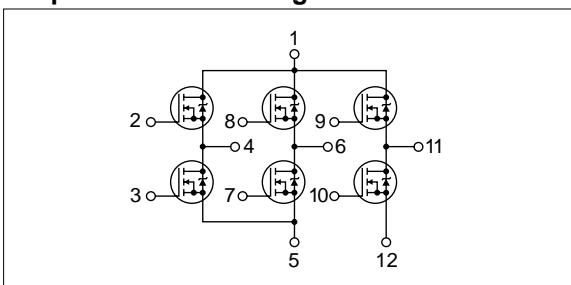
\* : V<sub>DD</sub>=25V, L=4.4mH, I<sub>D</sub>=7A, unclamped, R<sub>G</sub>=50Ω, see Fig. E on page 15.

## Electrical characteristics

(Ta=25°C)

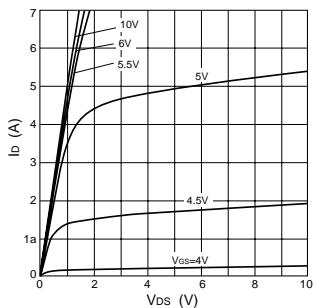
| Symbol               | Specification |     |      | Unit | Conditions   |
|----------------------|---------------|-----|------|------|--|
|                      | min           | typ | max  |      |  |
| V <sub>(BR)DSS</sub> | 250           |     |      | V    | I <sub>D</sub> =100μA, V <sub>GS</sub> =0V               |
| I <sub>GSS</sub>     |               |     | ±100 | nA   | V <sub>GS</sub> =±20V                                    |
| I <sub>DSS</sub>     |               |     | 100  | μA   | V <sub>DS</sub> =250V, V <sub>GS</sub> =0V               |
| V <sub>TH</sub>      | 2.0           |     | 4.0  | V    | V <sub>DS</sub> =10V, I <sub>D</sub> =1mA                |
| R <sub>e(yfs)</sub>  | 4.5           | 6.5 |      | S    | V <sub>DS</sub> =10V, I <sub>D</sub> =3.5A               |
| R <sub>DS(ON)</sub>  |               | 0.2 | 0.25 | Ω    | V <sub>GS</sub> =10V, I <sub>D</sub> =3.5A               |
| C <sub>iss</sub>     |               | 850 |      | pF   | V <sub>DS</sub> =10V,                                    |
| C <sub>oss</sub>     |               | 550 |      | pF   | f=1.0MHz,  |
| C <sub>rss</sub>     |               | 250 |      | pF   | V <sub>GS</sub> =0V                                      |
| t <sub>d(on)</sub>   |               | 20  |      | ns   | I <sub>D</sub> =3.5A,                                    |
| t <sub>r</sub>       |               | 25  |      | ns   | V <sub>DD</sub> =100V,                                   |
| t <sub>d(off)</sub>  |               | 90  |      | ns   | R <sub>L</sub> =28.6Ω, V <sub>GS</sub> =10V,             |
| t <sub>f</sub>       |               | 70  |      | ns   | see Fig. 3 on page 16.                                   |
| V <sub>SD</sub>      |               | 1.1 | 1.5  | V    | I <sub>D</sub> =7A, V <sub>GS</sub> =0V                  |
| t <sub>rr</sub>      |               | 85  |      | ns   | I <sub>D</sub> =3.5A, V <sub>GS</sub> =0V, di/dt=100A/μs |

## ■Equivalent circuit diagram

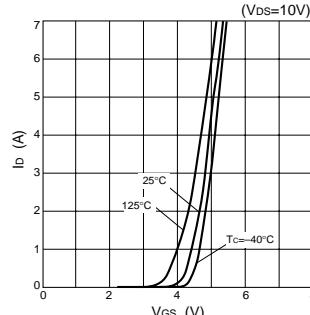


## Characteristic curves

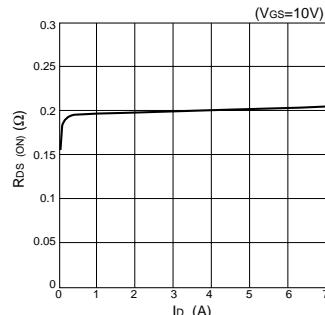
I<sub>D</sub>-V<sub>DS</sub> Characteristics (Typical)



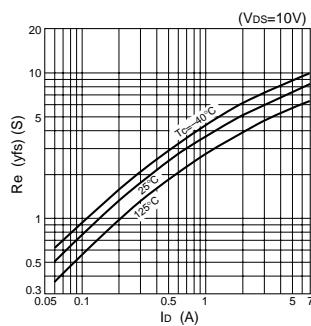
I<sub>D</sub>-V<sub>GS</sub> Characteristics (Typical)



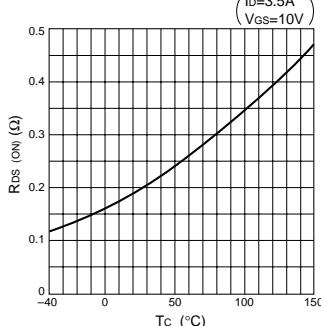
R<sub>DS(ON)</sub>-I<sub>D</sub> Characteristics (Typical)



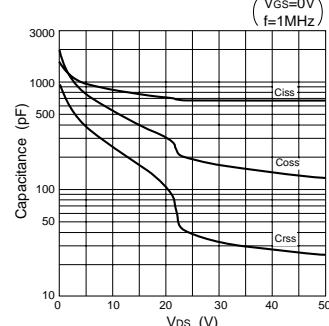
R<sub>e(yfs)</sub>-I<sub>D</sub> Characteristics (Typical)



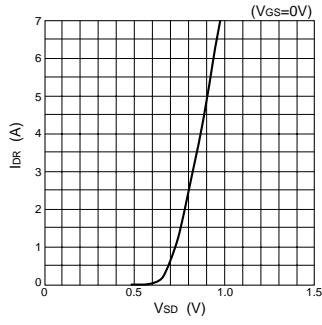
R<sub>DS(ON)</sub>-T<sub>c</sub> Characteristics (Typical)



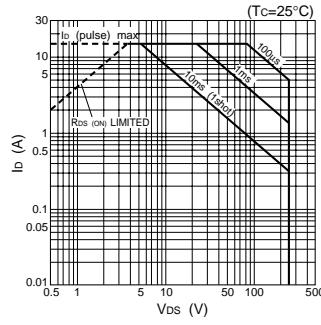
Capacitance-V<sub>DS</sub> Characteristics (Typical)



I<sub>DR</sub>-V<sub>SD</sub> Characteristics (Typical)



Safe Operating Area (SOA)



P<sub>T</sub>-T<sub>a</sub> Characteristics

